NSN 5961-01-177-3512

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-177-3512 **Inclosure Material:** Glass **Overall Length:** 0.570 inches **Terminal Length:** 1.312 inches **Overall Diameter:** 0.224 inches Joint Electronic Device Engineering Council/jedec/case Outline Designation: D0-13 **Mounting Method: Terminal Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 7.13 breakdown voltage, dc and 7.88 breakdown voltage, dc **Current Rating Per Characteristic:** 10.00 milliamperes all primaries horsepower metric **Power Rating Per Characteristic:** 1.0 watts any acceptable major **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius junction **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure:** Demilitarization: No